DATA SHEET



Solid State Relay OCMOS FET

PS7214-1A

4-PIN SOP, 1.0 Ω LOW ON-STATE RESISTANCE 1-ch Optical Coupled MOS FET

DESCRIPTION

The PS7214-1A is a low on-state resistance solid state relay containing a GaAs LED on the input side and MOS FETs on the output side.

It is suitable for PLC, etc. because of its large continuous load current and low on-state resistance.

FEATURES

- Low on-state resistance ($R_{on} = 1.0 \Omega \text{ TYP.}$)
- Large continuous load current (I_L = 400 mA)
- 1 channel type (1 a output)
- · Designed for AC/DC switching line changer
- Small and thin package (4-pin SOP, Height = 2.1 mm)
- High isolation voltage (BV = 1 500 Vr.m.s.)
- · Low offset voltage
- Ordering number of taping product: PS7214-1A-E3, E4, F3, F4

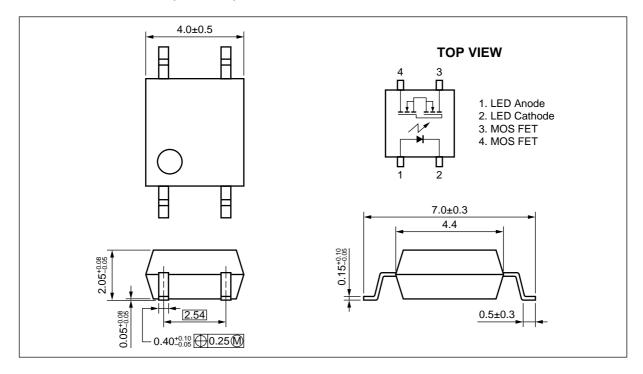
APPLICATIONS

- · Measurement equipment
- · FA equipment

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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

PACKAGE DIMENSIONS (Unit: mm)





ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number*1
PS7214-1A	4-pin SOP	Magazine case 100 pcs	PS7214-1A
PS7214-1A-E3		Embossed Tape 900 pcs/reel	
PS7214-1A-E4			
PS7214-1A-F3		Embossed Tape 3 500 pcs/reel	
PS7214-1A-F4			

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit	
Diode	Forward Current (DC)	lF	50	mA	
	Reverse Voltage	VR	5.0	V	
	Power Dissipation	Po	50	mW	
	Peak Forward Current*1	IFP	1	Α	
MOS FET	Break Down Voltage	VL	100	V	
	Continuous Load Current	lι	400	mA	
	Pulse Load Current*2 (AC/DC Connection)	ILP	0.8	А	
	Power Dissipation	Po	300	mW	
Isolation Voltage*3		BV	1 500	Vr.m.s.	
Total Power Dissipation		Рт	350	mW	
Operating Ambient Temperature		TA	-40 to +85	°C	
Storage Temperature		T _{stg}	-40 to +100	°C	

^{*1} PW = 100 μ s, Duty Cycle = 1 %

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^{*2} PW = 100 ms, 1 shot

^{*3} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60 % between input and output



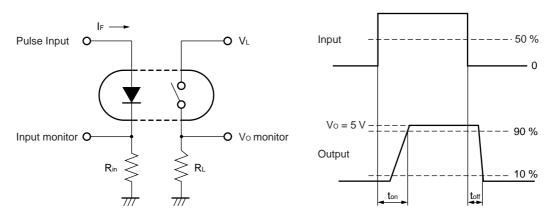
RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

ELECTRICAL CHARACTERISTICS (TA = 25 °C)

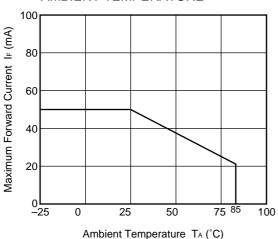
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	lR	V _R = 5 V			5.0	μΑ
MOS FET	Off-state Leakage Current	Loff	V _D = 100 V			1.0	μΑ
	Output Capacitance	Cout	V _D = 0 V, f = 1 MHz		120		pF
Coupled	LED On-state Current	IFon	IL = 400 mA			2.0	mA
	On-state Resistance	Ron	IF = 10 mA, IL = 400 mA, t ≤ 10 ms		1.0	1.2	Ω
	Turn-on Time*1	ton	If = 10 mA, Vo = 5 V, RL = 500 Ω ,		1.3	2.0	ms
	Turn-off Time*1	toff	PW ≥ 10 ms		0.1	1.0	
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10°			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.5		pF

*1 Test Circuit for Switching Time

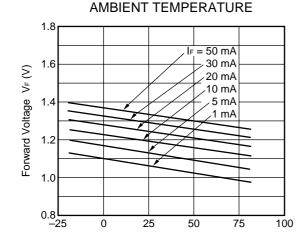


TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)



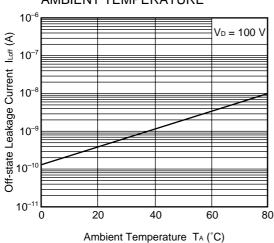


FORWARD VOLTAGE vs.

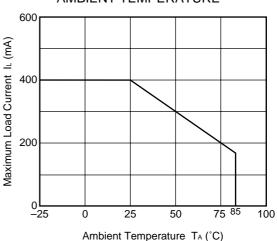


OFF-STATE LEAKAGE CURRENT vs. AMBIENT TEMPERATURE

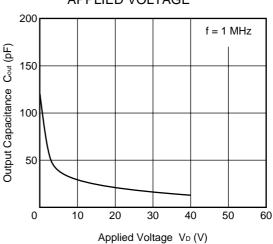
Ambient Temperature TA (°C)



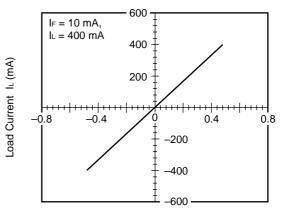
MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE



OUTPUT CAPACITANCE vs. APPLIED VOLTAGE



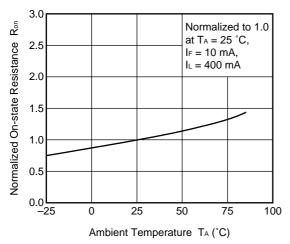
LOAD CURRENT vs. LOAD VOLTAGE



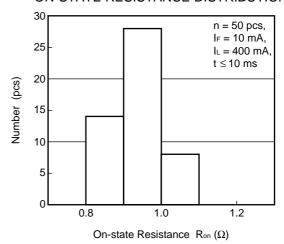
Load Voltage V_L (V)

NEC

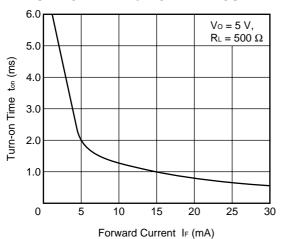
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



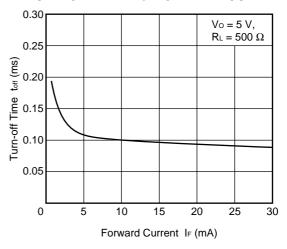
ON-STATE RESISTANCE DISTRIBUTION



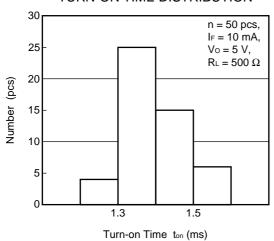
TURN-ON TIME vs. FORWARD CURRENT



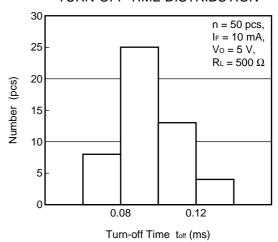
TURN-OFF TIME vs. FORWARD CURRENT



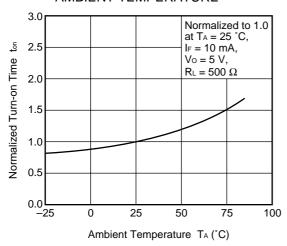
TURN-ON TIME DISTRIBUTION



TURN-OFF TIME DISTRIBUTION

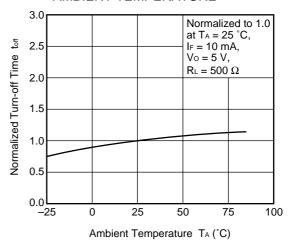


NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE

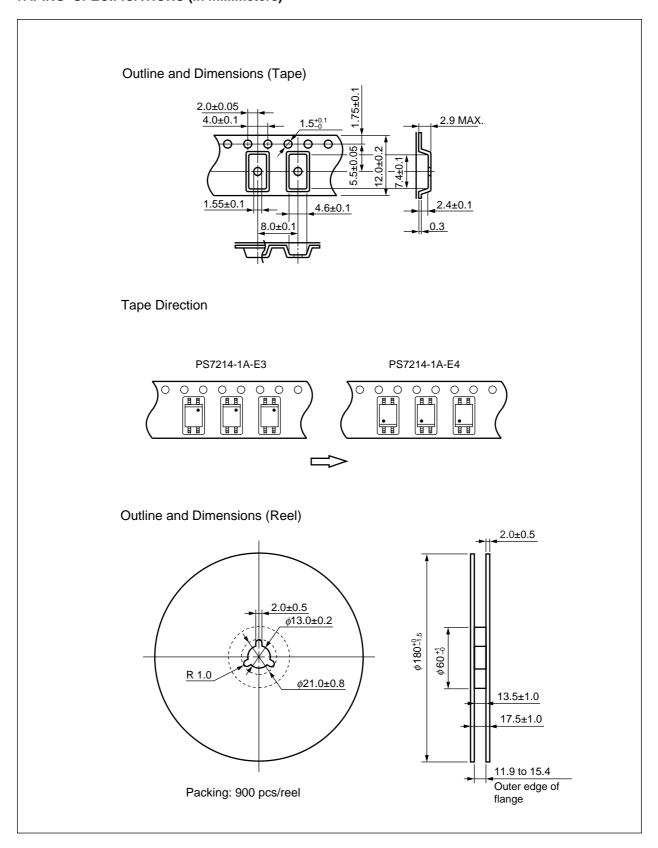


Remark The graphs indicate nominal characteristics.

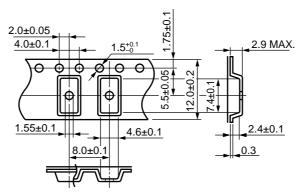
NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



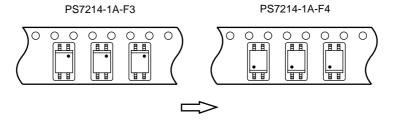
★ TAPING SPECIFICATIONS (in millimeters)



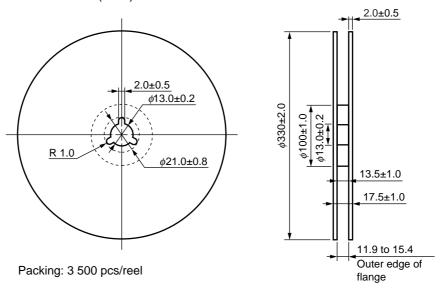
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)



* RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

Peak reflow temperature
 260°C or below (package surface temperature)

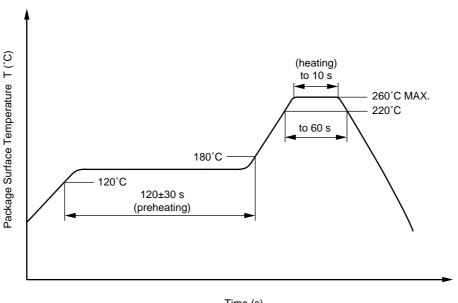
Time of peak reflow temperature
 Time of temperature higher than 220°C
 60 seconds or less

Time to preheat temperature from 120 to 180°C 120±30 s
 Number of reflows Three

Flux
 Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

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SAFETY INFORMATION ON THIS PRODUCT

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GaAs Products

The product contains gallium arsenide, GaAs.

GaAs vapor and powder are hazardous to human health if inhaled or ingested.

- Do not destroy or burn the product.
- Do not cut or cleave off any part of the product.
- Do not crush or chemically dissolve the product.
- Do not put the product in the mouth.

Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.

▶For further information, please contact

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